# Application Note 

# AN-EVAL 2x8-ISO1H816G-1 

Coreless Transformer Isolated High Side Switch Evaluation Board 2 x 8 Channel 1.2A with ISO1H816G

Published by Infineon Technologies AG
http://www.infineon.com

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## Introduction

## Application

This Application Note describes a Demoboard with an isolated $2 \times 8$ Channel 1.2A Digital Output. The board is designed to show the performance of the ISOFACE ${ }^{\circledR}$ Part ISO1H816G providing an Isolated Interface output to drive resistive, capacitive or inductive loads directly. The input can be driven by applying $3.3 \mathrm{~V} / 5 \mathrm{~V}$ CMOS compatible signals to connector K3. The input operates in Micro Controller Mode by using Chip Select and SCLK Signals. The Output consists of 2 times 8 Channel High Side Switches with 1.2A Current rating. The Output is protected with a channel selected over-temperature switch (to off).


Typical Application

## ISO1H816G

The ISO1H816G is a galvanic isolated 8-bit data interface in P-DSO-36 package that provides 8 fully protected high-side power switches that are able to handle currents up to 1.2A.
An SPI microcontroller ( $\mu \mathrm{C}$ ) compatible interface allows connecting the IC directly to a $\mu \mathrm{C}$ system. The input interface is designed to operate with $3.3 \mathrm{~V} / 5 \mathrm{~V}$ CMOS compatible levels. The data transfer from input to output side is realized by the integrated Coreless Transformer Technology.

This device includes 8 high-side power switches that are controlled by means of the integrated serial interface. The interface is 8 -bit $\mu \mathrm{C}$ compatible. The ISOFACE ${ }^{\circledR}$ can replace optocouplers and the 8 high-side switches in conventional I/O-Applications as galvanic isolation is implemented by means of the integrated coreless transformer technology. The $\mu \mathrm{C}$ compatible interface allows a direct connection to the ports of a microcontroller without the need for other components. Each of the 8 highside power switches is protected against short to Vbb , overload, over-temperature and against overvoltage by an active zener clamp.

[^0]

Figure 1- EVAL 2x8-ISO1H816G

## Board Characteristics

| Parameter | Min. | Max | Unit | Remarks |
| :--- | :---: | :---: | :---: | :--- |
| VCC Input VoItage | 3.0 | 5.5 | V | K4 Jumper 1-2 |
|  | 8 | 12 | V | K4 Jumper 2-3 |
| VBB Input Voltage | 11 | 45 | V |  |
| Input Signals | -0.3 | 0.3 xVCC | V | low level |
|  | 0.7 xVCC | $\mathrm{VCC}+0.3 \mathrm{~V}$ | V | high level |
| Output Current Limit | 1.4 | 4.5 | A |  |
| Output Clamping Voltage | 47 | 60 | V |  |

## Functional Description

## Power Supply

The Demo Board contains 2 galvanic isolated voltage domains that are independent from each other. The input interface is supplied by Pin1 and Pin14 of K3.
Jumper K4 selects direct supply from K3 Pin1 either with 3,3V/5V VCC (Jumper 1-2) or using the onboard 5 V voltage regulator (Jumper 2-3). The output stage is supplied at pin1 and 10 of K 2 , and K2 with Vbb voltage. The different voltage domains can be switched on at different times. The output stage is only enabled once the input stage enters a stable state.

## Serial Interface

The ISO1H816G contains a serial interface that can be directly controlled by the microcontroller output ports.

## SPI Signal Description

CS - Chip select. The system microcontroller selects the ISO1H816G by means of the CS pin. Whenever the pin is in a logic low state, data can be transferred from the $\mu \mathrm{C}$.

## CS High-to-low transition:

- Serial input data can be clocked in from then on
- SO changes from high impedance state to logic high or low state corresponding to the SO bit-state


## CS Low-to-high transition:

- Transfer of SI bits from shift register into output buffers, if number of clock signals was an integer multiple of 8
- SO changes from the SO bit-state to high impedance state

To avoid any false clocking, the serial input pin SCLK should be logic high state during high-to-low transition of CS. When CS is in a logic high state, any signals at the SCLK and SI pins are ignored and SO is forced into a high impedance state. The integrated modulo counter that counts the number of clocks avoids the take over of invalid commands caused by a spike on the clock line or wrong number of clock cycles. A command is only taken over after the low-to-high transition of the CS signal, if the number of counted clock cycles is an integer multiple of 8.
SCLK - Serial clock. The system clock pin clocks the internal shift register of the ISO1H816G. The serial input (SI) accepts data into the input shift register on the rising edge of SCLK while the serial output (SO) shifts the output information out of the shift register on the falling edge of the serial clock. It is essential that the SCLK pin is in a logic high state whenever chip select /CS makes any transition. The number of clock pulses will be counted during a chip select cycle. The received data will only be accepted, if exactly an integer multiple of 8 clock pulses were counted during CS is active.
SI - Serial input. Serial data bits are shifted in at this pin, the most significant bit first. SI information is read in on the rising edge of the SCLK. Input data is latched in the shift register and then transferred to the control buffer of the output stages.
SO - Serial output. SO is in a high impedance state until the CS pin goes to a logic low state. The data of the internal shift register are shifted out serially at this pin. The most significant bit will appear at first. The further bits will appear following the falling edge of SCLK.

## Daisy-chain Configuration

the connection of different ICs and a $\mu \mathrm{C}$ as shown below is called a daisy-chain. For this type of bustopology only one SPI interface of the $\mu \mathrm{C}$ for two or more ICs is needed. All ICs share the same clock and chip select port of the SPI master. That is all ICs are active and addressed simultaneously. The data out of the $\mu \mathrm{C}$ is connected to the SI of the first IC in the line. Each SO of an IC is connected to the SI of the next IC in the line.


Number of adressed ICs $=\mathrm{n}$
Number of necessary control and data ports $=3$
All ICs are adressed by the common chip select

## SPI 8 Bit Transfer Signal Timing



## Output Stage

Each channel contains a high-side vertical power FET that is protected by embedded protection functions. The continuous current for each channel is 1.2A (all channels ON).
Each output is independently controlled by an output latch and a common reset line via the pin /DIS that disables all eight outputs and reset the latches. A logic high input data bit turns the respective output channel ON. A logic low data bit turns that output channel OFF.

## Power Transistor Over-Voltage Protection

Each of the eight output stages has it own zener clamp that causes a voltage limitation at the power transistor when inductive loads are switched off. $\mathrm{V}_{\mathrm{ON}}$ is then clamped to 47 V (min.).

## Inductive and over-voltage output clamp (each channel)

Energy is stored in the load inductance.

$$
\mathrm{E}_{\mathrm{L}}=1 / 2 \times \mathrm{L} \times \mathrm{I}_{\mathrm{L}}^{2}
$$

## Inductive load switch-off energy dissipation (each channel)

While demagnetizing the load inductance, the energy dissipation in the DMOS with an approximate solution for $R_{L}>0$. is:

$$
\mathrm{E}_{\mathrm{AS}}=\frac{\mathrm{I}_{\mathrm{L}} \times \mathrm{L}}{2 \times \mathrm{R}_{\mathrm{L}}} \times\left(\mathrm{V}_{\mathrm{bb}}+\left|\mathrm{V}_{\mathrm{ON}(\mathrm{CL})}\right|\right) \times \ln \left(1+\frac{\mathrm{I}_{\mathrm{L}} \times \mathrm{R}_{\mathrm{L}}}{\left|\mathrm{~V}_{\mathrm{ON}(\mathrm{CL})}\right|}\right)
$$

## Power Transistor Over-current Protection

The outputs are provided with a current limitation that enters a repetitive switched mode after an initial peak current has been exceeded. The initial peak short circuit current limit $\mathrm{I}_{\mathrm{L}(\mathrm{SCp})}$ is set to a minimum of 1.4 A at $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$. During the repetitive mode, short circuit current limit $\mathrm{I}_{\mathrm{L}(\mathrm{SCr})}$ is set to 2.2 A (typ.). If this operation leads to an over-temperature condition, a second protection level ( $T_{j}>135^{\circ} \mathrm{C}$ ) will change the output into a low Pulse-Width Modulated duty cycle (selective thermal shutdown with restart) to prevent critical chip temperatures.

## Common Diagnostic Output

The over-temperature detection information of the channels is OR-wired in the common diagnostic output block. The information is send via the integrated coreless transformer to the input interface. The output stage at pin DIAG has an open drain functionality combined with a current source. The red LED D20 and D21 show the current state of the DIAG output.
LED ON: one of the Channels has over-temperature or the VBB Supply is below the operating range

## Connectors

K1, K2:

|  | K1 | K2 |
| :---: | :--- | :--- |
| 1 | VBB1 | VBB2 |
| 2 | OUT10 | OUT20 |
| 3 | OUT11 | OUT21 |
| 4 | OUT12 | OUT22 |
| 5 | OUT13 | OUT23 |
| 6 | OUT14 | OUT24 |
| 7 | OUT15 | OUT25 |
| 8 | OUT16 | OUT26 |
| 9 | OUT17 | OUT27 |
| 10 | GNDbb1 | GNDbb2 |

K3:

| 1 | + Vin/VCC |
| :---: | :--- |
| 2 | /DIS |
| 3 | ICS |
| 4 | SCLK |
| 5 |  |
| 6 | SI |
| 7 |  |
| 8 |  |
| 9 |  |
| 10 |  |
| 11 |  |
| 12 |  |
| 13 | SO |
| 14 | GNDCC |

K4:

| Jumper 1-2 | VCC 3,3V/5V |
| :--- | :--- |
| Jumper 2-3 | Vin 8V ...12V |

## Schematic




## PCB Layout and Assembly



Board Layout - Component Side


[^1]
## Bill of Material

| Nr. | Quant. | Position | Value | Package |
| :---: | :---: | :--- | :--- | :--- |
| 1 | 5 | C1, C4, C6, C7, <br> C8 | 100nF, 50V | 0805 |
| 2 | 2 | C36, C37 | 1uF, 50V | 0805 |
| 3 | 2 | C9, C10 | 10uF, 50V | SMD_E |
| 4 | 2 | C3, C35 | 10uF, 10V | 0805 |
| 4 | 16 | C11, C12, C13, <br> C14, C15, C16, <br> C17, C18, C23, <br> C24, C25, C26, <br> C27, C28, C29, <br> C30 | 10nF, 50V | ( |

## References

[1] ISO1H816G Coreless Transformer Isolated Digital Output 8 Channel 0.625A High Side Switch, Data Sheet, Infineon Technologies

## Change service

| Revision History |  |  |  |
| :--- | :--- | :--- | :--- |
| Application Note EVAL2x8-ISO1H816G-1 |  |  |  |
| Actual Release: V1.1 |  | Date: 15.02.2010 | Previous Release: |
| Page of <br> actual <br> Rel. | Page of <br> prev. Rel. | Subjects changed since last release |  |
| 11 | --------- | First Issue |  |
|  |  |  |  |

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## Edition 2006-08-28

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[^0]:    The diagnostic logic on the power chip recognizes the over-temperature information of each power transistor. That information is sent via the internal coreless transformer to the pin DIAG at the input interface.

[^1]:    Board Layout - Bottom Side (mirror view)

